

FULL PAPER

Reaction of CaSi₂ and FeCl₂ with additional NaCl to synthesis of β -FeSi₂/Si composites

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This work studied the impact of the molar ratio of $CaSi_2$ and $FeCl_2$ and additional NaCl under Ar atmosphere on the formation of β -FeSi₂/Si composites. Phase and microstructure of silicide were characterized by X-ray powder diffraction (XRD), scanning electron microscopy (SEM) and transmission electron microscopy (TEM), respectively. The results indicate that the formation of β -FeSi₂ was favored in the sample with a molar ratio of $CaSi_2/FeCl_2$ higher than 1 while β -FeSi₂ was not generated in the sample with a molar ratio of $CaSi_2/FeCl_2$ equal to 1. β -FeSi₂/Si composites, β -FeSi₂ growing on the surface of Si nanosheet bundles and the surface of Si nanosheets, were formed in the sample with a 1:0.5:2.2 molar ratio of $CaSi_2$, FeCl₂, and NaCl. ©2022 The Ceramic Society of Japan. All rights reserved.

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1. Introduction

Due to the enhanced optical and electrical properties, and physical properties such as surface area compared to those of the bulk materials, low-dimensional nanostructured materials have been widely studied for various field areas of science such as sensing devices, $^{1)-3}$ catalysis $^{4),5)}$ and energy storage devices. $^{6)-9)}$

Recently, various Si-based nanosheets or nanocomposites, which present modified optical properties and/or have excellent anode performance as lithium-ion (Li-ion) battery electrodes, have been synthesized by the solid-state reactions of $CaSi_2$ and metal chlorides.^{6),7),10)–14)} Oh et al.⁷⁾ synthesized various Si-based nanocomposites consisting of nanoflake-like Ca_xSi₂ particles and transition metal silicide (MSi_v; M: Ni, Fe or Mn) particles by heating CaSi₂ and metal (M) chlorides mixture in a sealed stainless-steel tube at 600 °C. Itahara et al.¹²⁾ prepared fine Mg₂Si/Si composite powders by the reaction of CaSi₂, MgCl₂, and Na at 650 °C. These fine Si-based composites exhibited good anode performance in Li-ion batteries.7),10)-12) A calciumbridged siloxane consisting of Ca-bridged and fragmented Si planes was obtained by a solid-state reaction of CaSi₂ and TaCl₅ at 215 °C, which shows tunable optical properties as well as stable Li-ion battery anode performance.^{6),13)} Additionally, Mg₂Si/Si composites containing Si nanosheet bundles and Mg₂Si deposits were synthesized via heating treatment CaSi₂ and MgCl₂ mixture in a sealed stainless-steel cell under Ar atmosphere at 650 °C.¹⁴⁾ The prepared Mg₂Si/Si composites affect the emission property of the Si nanosheets.¹⁴⁾ Therefore, the reaction of CaSi₂ and transition metal chlorides mixture is an effective method to acquire various Si-based nanosheets or nanocomposites.

FeSi_x/Si (FeSi_x: FeSi and α -FeSi₂) composites, as potential material for Li-ion battery anode, have been widely studied in recent years.^{15)–18)} These FeSi_x/Si composites synthesized by mechanical alloying method are composed of nanosized particles and exhibit excellent performance in Li-ion battery anode. This can be attributed to two main reasons. First, FeSir around Si could effectively buffer the volumetric change of the electrodes and then improve the cycling stability of the composite material.^{16)–18)} Second, FeSi_x could effectively improve the electrical conductivity of electrodes because the electrical resistance of FeSi_x (FeSi and α -FeSi₂) and Si is 2.6 \times 10¹ and 6.0 \times 10³ Ω cm, respectively.¹⁸⁾ Liu et al.¹⁹⁾ stated that nanosheets often have large exposed surfaces and specific facets when compared with nanoparticles, making them more attractive in energy devices. Tani et al.²⁰⁾ reported that the electrical resistivity of β -FeSi₂ is 1.38 × 10¹ Ω cm, which is slightly higher than the electrical resistance of FeSi and α -FeSi₂ $(2.6 \times 10^1 \,\Omega \,\mathrm{cm})$.¹⁸⁾ Therefore, it is expected that β -FeSi₂/

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Si composites containing nanosheet bundles could be synthesized and exhibit enhanced anode performance in Liion batteries. Additionally, because of the possible enhancement of the thermoelectromotive force by the quantum confinement effect,²¹⁾ it is also expected that fine β -FeSi2/Si composites containing nanosheet bundles could be used as the raw material for the nanostructured thermoelectric bulk materials. Itahara et al.¹⁰⁾ reported that Sibased composites containing iron silicide (FeSi and Fe₃Si) particles and Ca-Si or Si nanosheet bundles have been synthesized by the solid-state reaction of CaSi₂ and FeCl₂ mixture and presented good anode performance in Li-ion batteries. It is expected that β -FeSi₂/Si composites could be synthesized based on the reaction of CaSi₂ and FeCl₂. The phase nucleation, phase sequence or phase selection for the formation of iron silicide have been intensively investigated between the metal and silicon diffusion couple. For example, Zhang et al.²²⁾ found that Fe₃Si was initially formed between the bulk diffusion couple of Fe-Si at 700 °C. Walser et al.23) reported that the first nucleation phase between Fe-Si thin film was FeSi. They discussed the formation of FeSi based on a combination of thermodynamic and kinetic considerations, which was also used to discuss the formation of other silicide nanostructures.²⁴⁾ However, the formation of β -FeSi₂ is usually very difficult and takes a very long time, which is related to the large nucleation barrier of β -FeSi₂.^{25),26)}

Yamada et al.²⁷⁾ synthesized β -FeSi₂ powder by annealing the Fe and Si mixture in Na melt at 500-800 °C under an Ar atmosphere and explained that the formation of β -FeSi₂ powder is because Si dissolved in the Na melt react with Fe powder. In addition, various silicide powder, such as α -MoSi₂ and β -MoSi₂,²⁸⁾ β -SiC,²⁹⁾ CrSi₂, MnSi_{1.7+ δ}, and CoSi³⁰ have been prepared using Na melt/flux at low temperature, which is also due to the reaction of Si dissolved in Na melt and metal powder. These researches suggest that Si dissolved in Na melt probably has higher activity. Harada et al.³¹⁾ found Si material can be prepared by the reaction of CaSi2 and NaCl according to the reaction formula: $CaSi_2 + NaCl \rightarrow 2Si + CaCl_2 + 2Na$ and stated that the generated Na dissolves rapidly in the molten salt containing NaCl and the side reaction between Na and Si probably hardly occurs. Fine iron silicide composites containing nanosheets have been obtained by the reaction of CaSi₂ and FeCl₂ in the molar ratio of 1:1 (the molar ratio of Si/Fe is 2:1).^{10),32)} Based on these researches, we expect that by decreasing FeCl2 amount, unreacted CaSi2 reacts with additional NaCl to form Na, which could dissolve in molten NaCl-CaCl₂ salts (CaCl₂ is formed from the reaction of CaSi₂ and FeCl₂) to form Na-NaCl-CaCl₂ liquid phase. And then Si dissolved in Na-NaCl-CaCl₂ liquid phase probably reacts with iron silicide (Fe₃Si and FeSi) to form β -FeSi₂. Additionally, for Fe–Si system, the Fe/Si supply ratio and thermal treatment condition dependences for the phase selection have been examined, and the silicide phase control and the multiple phase formation of the Fe-silicides have been reported.³³⁾⁻³⁸⁾ Therefore, decreasing FeCl₂ amount means that the molar ratio

of Si/Fe is higher than 2:1, probably contributing to the formation of Si-rich phase (β -FeSi₂). Hence, in present study, the impact of the molar ratio of CaSi₂ and FeCl₂ and additional NaCl on the formation of β -FeSi₂ was emphasized on.

2. Experimental procedure

2.1 Material preparation

CaSi₂ (99%), FeCl₂ (99.9%), and NaCl (99.9%) used in this study are high purity chemicals from Kojundo Chemical Lab. Co., Ltd. in Japan. CaSi₂, FeCl₂ and NaCl powders were weighted in molar ratio of 1:0.5:2.2, 1:0.75:2.2 and 1:1:2.2, respectively, and named F-0.5, F-0.75 and F-1, respectively. The molar ratio of $CaSi_2/$ NaCl was fixed while the molar ratio of CaSi2/FeCl2 $(x_{\text{CaSi}_2/\text{FeCl}_2})$ was changed between 1 and 2 $(x_{\text{CaSi}_2/\text{FeCl}_2})$ 1-2), which means that the molar ratio of Si/Fe is between 2:1 to 4:1. The weighted powders were ground by a corundum mortar and pestle for 1 min, put into a glass quartz tube, and then sealed in stainless-steel cell under Ar atmosphere with the detected oxygen level of less than 0.1 %. The cells were annealed at 850 °C for 1-3 h in furnace with a heating rate of 10 °C/min from room temperature to 850 °C. After heating, the heaters were turned off, and then samples were naturally cooled in furnace. In addition, the mixture of CaSi2 and NaCl powders in molar ratio of 1:2.2 (named F-0) was prepared and annealed at 850 °C for 1 h. After annealing, the treated samples were immersed in deionized water for 1 h under mild stirring to remove chlorides, and then filtrated, washed another three times by deionized water and one time by ethanol, and dried in air overnight.

2.2 Sample characterization

Phases of samples were characterized by Rigaku X-ray powder diffraction (XRD) operated at 40 kV and 20 mA with Cu K α radiation in the range of 5–80° with a step of 0.02°. The morphological and structural properties of the nanosheet bundles were characterized by field-emission scanning electron microscopy (SEM: JEOL JSM-7001F) with energy dispersion spectroscopy (EDS), conventional transmission electron microscopy (TEM: JEOL JEM 2100F), high-resolution TEM (HRTEM), and scanning transmission electron microscopy (STEM) with EDS. For the TEM sample preparation, the products were dispersed in a small amount of ethanol, then transferred onto a lacey carbon-coated copper grid and dried.

3. Results

Figure 1 presents XRD patterns of samples F-0.5, F-0.75 and F-1 after annealing at 850 °C for 1 h and washing.

 Table 1. The molar ratio of various samples

			1
Sample	CaSi ₂	FeCl ₂	NaCl
F-1	1	1.00	2.2
F-0.75	1	0.75	2.2
F-0.5	1	0.50	2.2
F-0	1	—	2.2



Fig. 1. XRD patterns of samples F-0.5, F-0.75 and F-1 after annealing at $850 \,^{\circ}$ C for 1 h and washing.



Fig. 2. XRD patterns of samples F-0.5, F-0.75 and F-1 after annealing at 850 °C for 3 h and washing.



Fig. 3. (a, b, c) SEM images and (d) EDS mappings of the sample F-1 after annealing at 850 °C for 3 h and washing (NSB: nanosheet bundles; MP: microsized particles).

Diffraction peaks corresponding to Si, FeSi, and Fe₃Si were detected in the sample F-1. On the other hand, diffraction peaks of β -FeSi₂ were observed in samples F-0.75 and F-0.5. Specifically, diffraction peaks related to β -FeSi₂, FeSi and Si were observed in the sample F-0.75. Diffraction peaks of β -FeSi₂, tr6-CaSi₂ (a crystal structure of CaSi₂), Si and a small peak of FeSi were detected in the sample F-0.5. These results illustrate that the formation of β -FeSi₂ is favored when $x_{CaSi_2/FeCl_2}$ is larger than 1.

Figure 2 shows XRD patterns of samples F-0.5, F-0.75 and F-1 after annealing at 850 °C for 3 h and washing. Si, FeSi, and Fe₃Si peaks were observed in the sample F-1. By contrast, β -FeSi₂ peaks were detected in samples F-0.75 and F-0.5. For example, β -FeSi₂, FeSi, and Si peaks were observed in the sample F-0.75. Peaks of β -FeSi₂, Si and a small peak of FeSi were observed in the sample F-0.5. Tr6-CaSi₂ peaks disappeared in the sample F-0.5 when extended annealing time from 1 h (Fig. 1) to 3 h (Fig. 2), which suggests that CaSi₂ could react with NaCl as the previous report.³¹⁾ These results also demonstrate that the generation of β -FeSi₂ is favorable when $x_{CaSi_2/FeCl_2}$ is larger than 1.

Figure 3 presents microstructure of the sample F-1 after annealing at 850 °C for 3 h and washing. **Table 2** lists EDS results in Fig. 3. As shown in Fig. 3(a), nanosheet bundles and microsized particles can be clearly identified in the sample F-1. It can be seen from EDS mappings [Fig. 3(d)] that Fe and Si were detected on the nanosheet

bundles, suggesting the formation of iron silicide on the surface of Si nanosheet bundles. Based on the EDS spot analysis (Table 2), FeSi (points 1 and 2) was detected on the surface of Si nanosheet bundles [Fig. 3(b)] while Fe₃Si (points 4, 5 and 6) was detected on the microsized particles [Fig. 3(c)]. These results illustrate that β -FeSi₂ is not formed when $x_{CaSi_2/FeCl_2}$ is equal to 1.

Detailed microstructure of the sample F-0.5 after annealing at 850 °C for 3 h and washing is presented in **Fig. 4**. EDS results of the selected points are listed in **Table 3**. Nanosheet bundles and microsized particles were detected in the sample F-0.5, which is similar to the products of the sample F-1 (Fig. 3). Fe and Si were observed on the surface of nanosheet bundles and microsized particles [Fig. 4(d)]. Based on EDS spot analyses (Table 3), it is confirmed that the microsized particles and the particles grown on the surface of nanosheet bundles are β -FeSi₂. Some incomplete particles containing Ca, Si and O were

Table 2. EDS spot analyses of selected points in Fig. 3 (at %)

Element	1	2	3	4	5	6
Fe	49.88	43.65	1.42	69.91	67.80	69.58
Si	47.87	50.59	74.71	28.26	29.16	28.01
0	2.26	5.76	23.87	1.83	3.05	2.41

Table 3. EDS spot analyses of selected points in Fig. 4 (at %)

Element	1	2	3	4	5	6
Fe	27.00	32.06	29.65	28.89	28.73	30.79
Si	57.55	63.07	58.05	57.05	62.88	60.06
0	15.45	4.86	12.30	14.06	8.39	9.16

observed [marked with red circles in Fig. 4(a)], which should be related to unreacted CaSi₂ phase. The distribution of some Ca was consistent with the distribution of Cl, which can be considered as remained CaCl₂ because of inefficient washing. Na was also heterogeneously distributed on the composites and the distribution of Na was consistent with that of Cl, which is considered remained NaCl due to the inefficient washing. These results demonstrate that β -FeSi₂ is formed when $x_{CaSi_2/FeCl_2}$ is larger than 1.

Figure 5 presents STEM images, HRTEM and EDS mappings of the nanosheet pieces after exfoliating from the nanosheet bundles in the sample F-1 after annealing at 850 °C for 3 h and washing. EDS mappings indicate that Fe unevenly distributed on the part of surface of nanosheet (nanosized black dots) and the distribution of Fe mainly coincided with Si and O. HRTEM image with an FFT pattern of the nanosized black dot grown on the Si nanosheet [Fig. 5(b)] illustrates that two patterns of β -FeSi₂ are superimposed. The plane spacing of about 0.48 and 0.18 nm was observed, which is related to the lattice spacing of (111) and (241) lattice planes of β -FeSi₂, respectively, according to the diffraction spots indexed in the FFT pattern. The zone axis direction was perpendicular to (110), somewhat inclined. Si nanosheets with exposed Si (111) planes synthesized by extracting Ca atoms from layered CaSi₂ have been reported everywhere.^{39),40)} Numerous researches⁴¹⁾⁻⁴⁴⁾ have studied the epitaxial growth of β -FeSi₂ layer on Si (111) substrate and reported that (101) β -FeSi₂ or (110) β -FeSi₂ // (111) Si. In the actual β -FeSi₂ crystal, the rotation along an axis by 90° usually occurs. The observation directions of β -FeSi₂ were near (101) or



Fig. 4. (a, b, c) SEM images and (d) EDS mappings of the sample F-0.5 after annealing at 850 °C for 3 h and washing (NSB: nanosheet bundles; MP: microsized particles).



Fig. 5. (a) STEM image and EDS mappings of a piece of nanosheet after exfoliating from the sample F-0.5 annealed at $850 \,^{\circ}$ C for 3 h, and (b) HRTEM and its FFT pattern of black dot.

(110), which is nearly parallel to the sheet surface. This closely agree with the epitaxial relationship (101) or (110) β -FeSi₂ // (111) Si. The existence of such growth variants shows that the β -FeSi₂ nanoparticles were epitaxially grown on the crystalline Si nanosheets.

The Si and O around β -FeSi₂ nanoparticles may be related to amorphous SiO_x. In addition, the distribution of Ca and Na found on the nanosheet was consistent with Cl, which can be considered that CaCl₂ and NaCl remained around the nanosheets by insufficient washing. The TEM results illustrate that β -FeSi₂ was also formed on the surface of nanosheets of the nanosheet bundles in the sample F-0.5 after annealing at 850 °C for 3 h.

4. Discussion

As shown in Figs. 1 and 2, Si, FeSi and Fe₃Si were formed in the sample F-1 after annealing at 850 °C for 1 and 3 h. By contrast, β -FeSi₂ was formed in samples F-0.5 and F-0.75 after annealing at 850 °C for 1 and 3 h, which illustrates that the formation of β -FeSi₂ is favored when $x_{CaSi_2/FeCl_2}$ is higher than 1. It has been reported that CaSi₂ can react with FeCl₂ in the molar ratio of 1:1.¹⁰ Compared with the sample F-1, unreacted CaSi₂ in samples F-0.5 and F-0.75 could further react with NaCl to form Na in the heating process.³¹ Therefore, the formed Na dissolved in molten NaCl–CaCl₂ salts to form Na–NaCl–CaCl₂ liquid phase in samples F-0.5 and F-0.75 probably contributes to the formation of β -FeSi₂.

It can be seen from Fig. 6(a) that starting CaSi₂ consists of tr3-CaSi2, tr6-CaSi2, and less amount of Si. Tr6-CaSi2 peaks and a weak Si peak were detected in CaSi2 after annealing at 850 °C for 1 h. CaSi2 has a trigonal structure and contains two polymorphs (tr3-CaSi2 and tr6-CaSi2) at atmosphere pressure based on the stacking of Ca layers. The stacking of trigonal Ca layers follows an ABC sequence with a three-layer repeat distance in the tr3 structure and follows an AABBCC sequence with a six-layer repeat distance in the tr6 structure.45) Tr6-CaSi2 is more stable than tr3-CaSi2, and tr6-CaSi2 stabilizes over tr3-CaSi2 with higher temperature according to the calculated Gibbs free energy.⁴⁶ Therefore, tr3-CaSi₂ transformed into tr6-CaSi₂ in the heating process. Strong Si peaks were observed in the sample F-1, which illustrate that CaSi₂ can react with NaCl at 850 °C. Unreacted CaSi2 in the sample F-0.5 disappeared after prolonging annealing time from 1 h (Fig. 1) to 3 h (Fig. 2) also illustrating that CaSi₂ can react with NaCl at 850 °C.

Noted in Fig. 6(b), tr6-CaSi₂, Si, CaCl₂, NaCl, NaO₃ and NaO₂ peaks were observed in the sample F-0 after annealing at 850 °C for 1 h before washing. The eroded glass quartz tube (the insert image) and the generated oxidized sodium (NaO₃ and NaO₂) demonstrate the formation of Na. The products of F-0 were consistent with the reaction formula: $CaSi_2 + NaCl \rightarrow 2Si + CaCl_2 + 2Na$ in previous report.³¹⁾ The eroded glass quartz tube below sample height was probably because of the reaction of glass and Na dissolved in molten CaCl2-NaCl salts, and the eroded glass quartz tube above sample height may be related to Na vapor reacted with glass, which is due to the higher vapor pressure of Na at high temperatures, for example, the vapor pressure of Na at 827 °C (1100 K) and 927 °C (1200 K) is 0.21 and 1 bar,⁴⁷⁾ respectively. These results confirmed that CaSi2 can react with NaCl to form Na

Figure 7 presents the microstructure of the sample F-0 after annealing at 850 °C for 1 h and washing. Porous particles were observed in the sample F-0. Based on the EDS mappings [Fig. 7(d)], these porous particles were mainly Si. Some unreacted CaSi₂ particles were also detected [Fig. 7(c)], which is consisted with XRD results in Fig. 6. These unreacted CaSi₂ particles were incomplete and had



Fig. 6. (a) XRD patterns of raw $CaSi_2$, and raw $CaSi_2$ and the sample F-0 after annealing at 850 °C for 1 h and washing, and (b) XRD patterns and appearance of glass quartz tube (insert image, the red rectangle represents the height of sample) of the sample F-0 after annealing at 850 °C for 1 h before washing.

porous silicon on the surface. Si nanosheet bundles obtained by the reaction of CaSi2 and chlorides have been reported everywhere^{6),7),10)-14)} because of Ca is extracted from CaSi2 by chlorides. However, the morphology of porous Si particles formed by the reaction of CaSi₂ and NaCl were different from Si nanosheet bundles in previous reports. Similarly, incomplete unreacted CaSi2 particles were observed in the sample F-0.5 after annealing at 850 °C for 3 h [Fig. 4(a)]. By contrast, those Si nanosheet bundles with β -FeSi₂ grown on the surface are relatively intact. MacCaldin et al.48) reported that the solubility of Si in Na melt at 800 °C was estimated to be 10-20 atomic %. The formation of porous Si particles and incomplete unreacted CaSi₂ particles suggests that Si can dissolve in Na-NaCl-CaCl₂ liquid phase, especially for the Si generated form the reaction of CaSi₂ and NaCl.

Figure 8 presents XRD patterns and appearance of glass quartz tube of samples F-0.5, F-0.75 and F-1 after annealing at $850 \,^{\circ}$ C for 3 h before washing. Oxidized sodium peaks were observed in samples F-0.5 (NaO₃ and NaO₂) and F-0.75 (NaO₃) and the glass tubes of samples F-0.5 and F-0.75 were eroded. These results demonstrate

that Na generated in samples F-0.5 and F-0.75. On the other hand, no oxidized sodium peaks were detected and the glass quartz tube was not eroded in the sample F-1, which illustrates that Na is not generated in the sample F-1. It has been demonstrated that Si can dissolve in molten NaCl, or MnCl₂, or MgCl₂ salt around 800 °C, especially in the presence of O_2 .⁴⁹⁾ As shown in Figs. 1 and 2, no β -FeSi₂ was formed in the sample F-1 after annealing at 850 °C for 1–3 h, illustrating that β -FeSi₂ was not generated in molten NaCl-CaCl₂ salts in short time (3 h). By contrast, β -FeSi₂ was formed in samples F-0.5 and F-0.75, illustrating that β -FeSi₂ was formed in Na–NaCl–CaCl₂ liquid phase, which is because Si dissolved in Na-NaCl-CaCl₂ liquid phase probably more active to react with iron silicide (Fe₃Si and FeSi) grown on the surface of Si nanosheet bundles and microsized particles to form β -FeSi₂.

In addition, based on the starting material listed in **Table 1**, the molar ratio of Si/Fe in samples F-0.5, F-0.75 and F-1 was 4:1, 3:1 and 2:1 respectively. Numerous researchers^{37),50)} reported that β -FeSi₂ film grown on Si substrate were obtained at low temperature (530 or 630 °C)



Fig. 7. (a, b, c) SEM images and (d) EDS mappings of the sample F-0 after annealing at 850 °C for 1 h and washing.



Fig. 8. (a) XRD patterns and (b) appearance of glass quartz tube of samples F-0.5, F-0.75 and F-1 after annealing at $850 \,^{\circ}$ C for 3 h before washing (the red rectangles represent the height of samples).

using Fe-Si co-deposition method (the molar ration Si/Fe is around 2:1). However, it has been reported that peaks of Fe, Si and Fe₃Si were detected after annealing the mixture of Fe powder ($< 45 \,\mu m$) and Si powder ($< 70 \,\mu m$) (the molar ratio of Si/Fe is 2:1) without Na at 800 °C for 24 h in a sealed stainless-steel tube under Ar atmosphere.²⁷⁾ These results illustrate that the activity and uniformity of nanoscale Si/Fe layer may be different from microsized Si and Fe particles. Theoretically, Si-rich phase could increase the contact area of Si and iron silicide (FeSi and Fe₃Si) and decrease the diffusion distance of Si, which is probably contributed to the formation of β -FeSi₂. As shown in Fig. 3, microsized FeSi particles formed on the surface of Si nanosheet bundles [Fig. 3(b)] in the sample F-1 can be called Si-rich phase when compared with Fe₃Si microsized particles [Fig. 3(c)]. However, β -FeSi₂ was not formed on the surface of Si nanosheet bundles in the sample F-1 [Fig. 3(b)], although it was annealed at 850 °C for 3 h. This is probably because of the nucleation difficulties of β -FeSi₂.^{25),26)} Therefore, the main reason for the formation of β -FeSi₂ in samples F-0.5 and F-0.75 is because Si dissolved in Na-NaCl-CaCl₂ liquid phase react with iron silicide (Fe₃Si and FeSi) grown on the surface of Si nanosheet bundles and microsized particles to form β -FeSi₂. As shown in Figs. 4(a) and 7, incomplete unreacted CaSi₂ particles [Fig. 4(a)] and porous Si (Fig. 7) indicate that Si generated by the reaction of CaSi2 and NaCl may be more soluble in Na-NaCl-CaCl₂ liquid phase, which protects the Si nanosheet bundles with β -FeSi₂ layer on the surface (Fig. 4).

Noted in Fig. 5, nanosized β -FeSi₂ particles grown on the surface of Si nanosheet bundles was consisted with the epitaxial relationship of (101) or (110) β -FeSi₂ // (111) Si. Numerous researchers^{25),26),42),51)} reported that epitaxial growth of β -FeSi₂ film on Si (111) substrate by depositing a few nanometers iron onto a silicon substrate and annealing. In addition, epitaxial growth of β -FeSi₂ nanodots (~2 nm high and ~8 nm wide) on Si (111) substrate were obtained by depositing Fe on Si nanodots on oxidized Si (111) surfaces and annealing.⁵²⁾ Therefore, the nanosized β -FeSi₂ grown on the Si (111) nanosheet was probably because Si diffused from Si (111) nanosheet to deposited iron or iron silicide (Fe₃Si and FeSi) nanoparticles to form β -FeSi₂.

5. Conclusion

The influence of the molar ratio of CaSi₂ and FeCl₂ powders and additional NaCl on the formation of β -FeSi₂ under Ar atmosphere were systematically studied in this work. β -FeSi₂/Si composites (β -FeSi₂ grown on the surface Si nanosheet bundles and the surface of Si nanosheets) were formed in the sample with a 1:0.5:2.2 molar ratio of CaSi₂, FeCl₂ and NaCl. The formation of β -FeSi₂ was favored in the sample with a molar ratio of CaSi₂/FeCl₂ higher than 1, whereas β -FeSi₂ was not formed in the sample with a molar ratio of CaSi₂/FeCl₂ equal to 1. This is because unreacted CaSi₂ in the sample with a molar ratio of CaSi₂/FeCl₂ higher than 1 could react with NaCl to form Na and then dissolve in molten NaCl–CaCl₂ salts to form Na–NaCl–CaCl₂ liquid phase. Si dissolved in Na–NaCl–CaCl₂ liquid phase should be more active to react with iron silicide (Fe₃Si and FeSi) to form β -FeSi₂.

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